



# 2SK4198FS — N-Channel Silicon MOSFET

## General-Purpose Switching Device Applications

### Features

- Low ON-resistance, low input capacitance, ultrahigh-speed switching.
- Adoption of high reliability HVP process.
- Attachment workability is good by Mica-less package.
- Avalanche resistance guarantee.

### Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		600	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±30	V
Drain Current (DC)	I <sub>DC</sub> *1	Limited only by maximum temperature T <sub>ch</sub> =150°C	5	A
	I <sub>Dpack</sub> *2	T <sub>c</sub> =25°C (SANYO's ideal heat dissipation condition)*3	4	A
Drain Current (Pulse)	I <sub>DP</sub>	PW≤10μs, duty cycle≤1%	18	A
Allowable Power Dissipation	P <sub>D</sub>		2.0	W
		T <sub>c</sub> =25°C (SANYO's ideal heat dissipation condition)*3	30	W
Channel Temperature	T <sub>ch</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C
Avalanche Energy (Single Pulse) *4	E <sub>AS</sub>		55	mJ
Avalanche Current *5	I <sub>AV</sub>		4.5	A

Note : \*1 Shows chip capability.

\*2 Package limited.

\*3 SANYO's condition is radiation from backside.

The method is applying silicone grease to the backside of the device and attaching the device to water-cooled radiator made of aluminium.

\*4 V<sub>DD</sub>=50V, L=5mH, I<sub>AV</sub>=4.5A

\*5 L≤5mH, Single pulse

Marking : K4198

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# 2SK4198FS

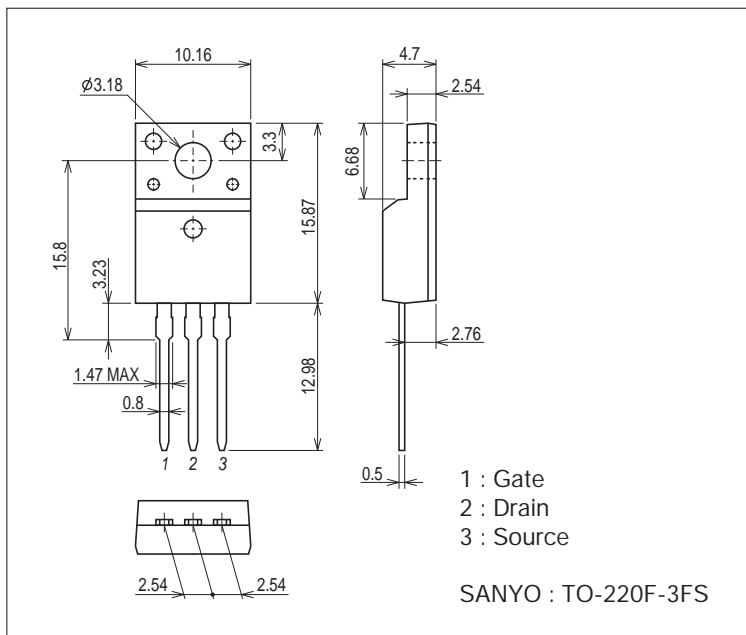
## Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=10mA, V_{GS}=0V$	600			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=480V, V_{GS}=0V$			100	$\mu A$
Gate-to-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 30V, V_{DS}=0V$			$\pm 100$	nA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V, I_D=1mA$	3		5	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V, I_D=2.5A$	1.2	2.4		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)}$	$I_D=2.5A, V_{GS}=10V$		1.8	2.34	$\Omega$
Input Capacitance	$C_{iss}$	$V_{DS}=30V, f=1MHz$		360		pF
Output Capacitance	$C_{oss}$	$V_{DS}=30V, f=1MHz$		69		pF
Reverse Transfer Capacitance	$C_{rss}$	$V_{DS}=30V, f=1MHz$		15		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		13		ns
Rise Time	$t_r$	See specified Test Circuit.		28		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit.		39		ns
Fall Time	$t_f$	See specified Test Circuit.		15		ns
Total Gate Charge	$Q_g$	$V_{DS}=200V, V_{GS}=10V, I_D=5A$		14.3		nC
Gate-to-Source Charge	$Q_{gs}$	$V_{DS}=200V, V_{GS}=10V, I_D=5A$		3.0		nC
Gate-to-Drain "Miller" Charge	$Q_{gd}$	$V_{DS}=200V, V_{GS}=10V, I_D=5A$		8.2		nC
Diode Forward Voltage	$V_{SD}$	$I_S=5A, V_{GS}=0V$		0.9	1.2	V

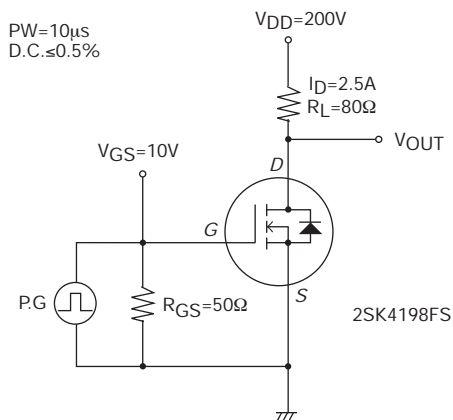
## Package Dimensions

unit : mm (typ)

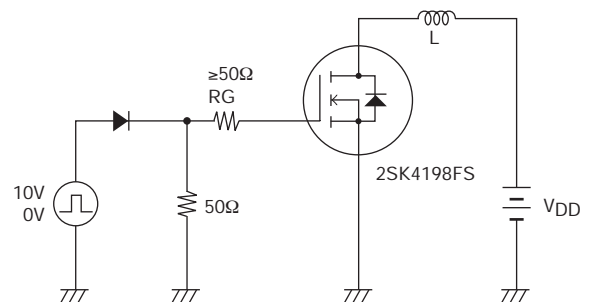
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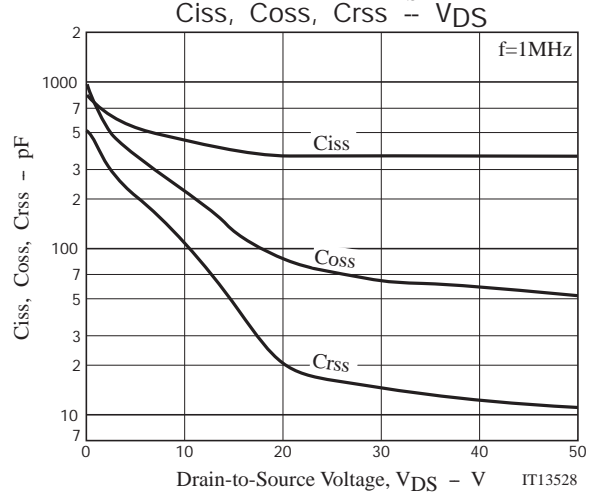
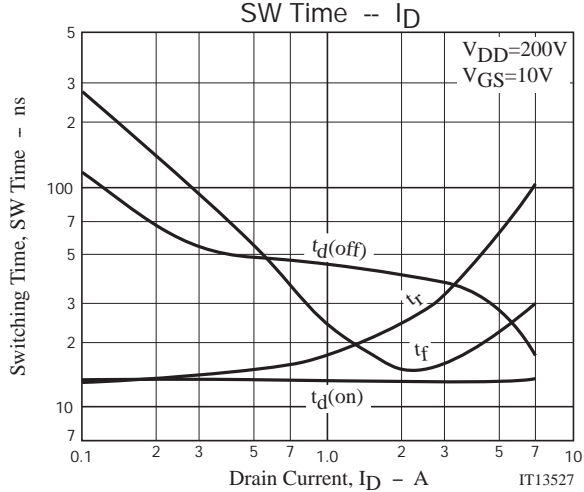
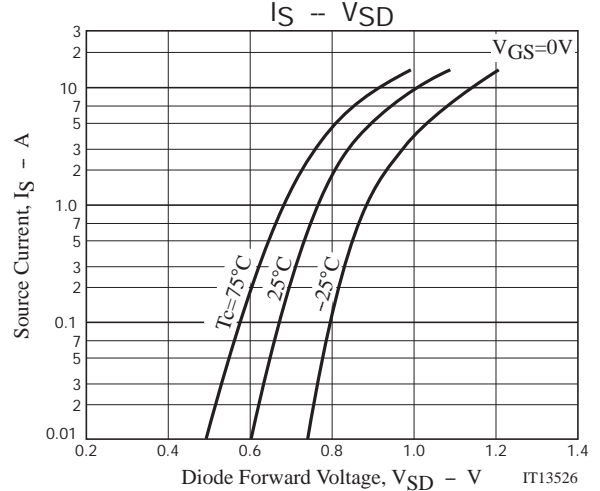
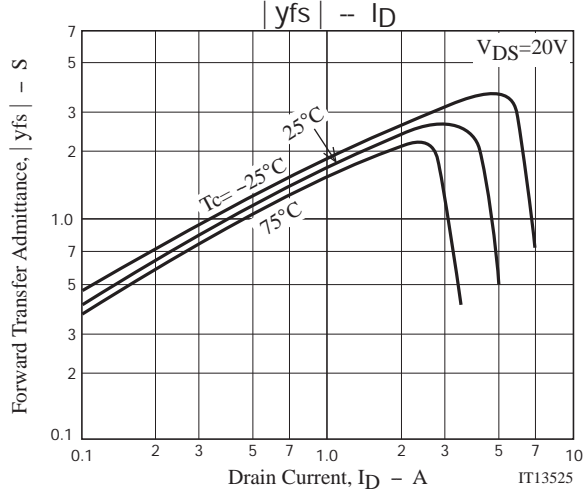
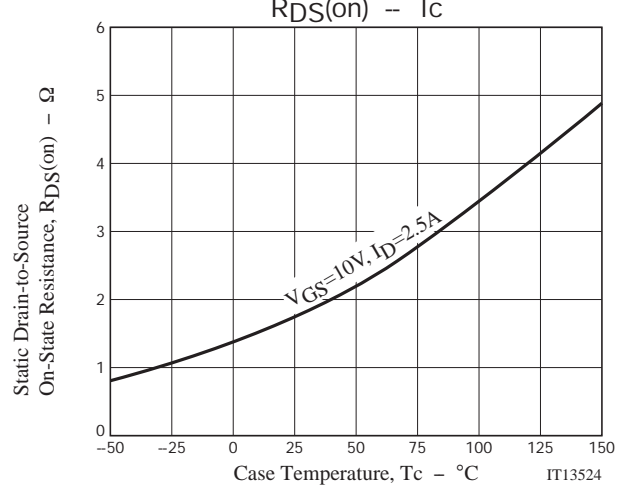
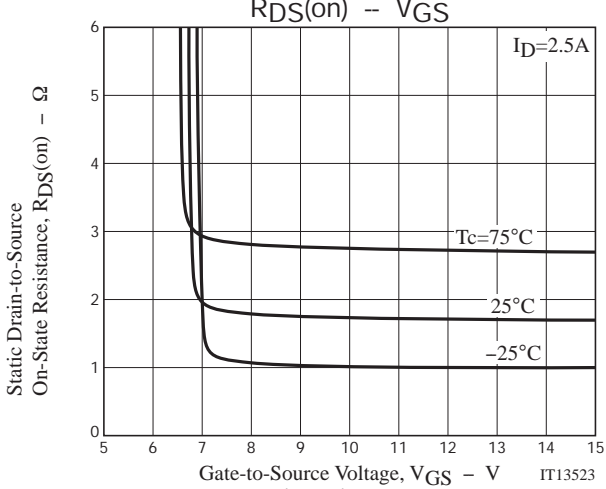
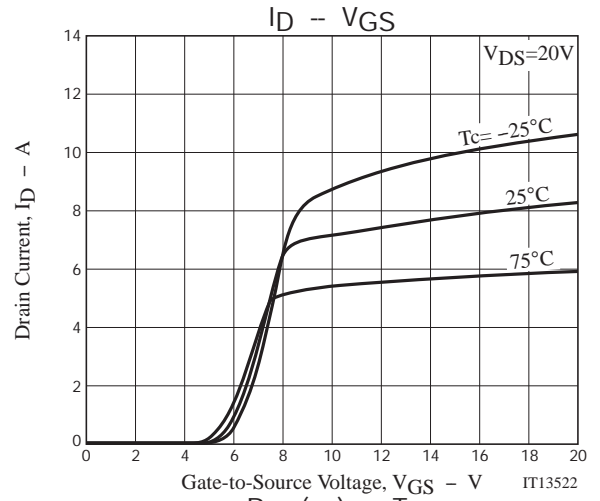
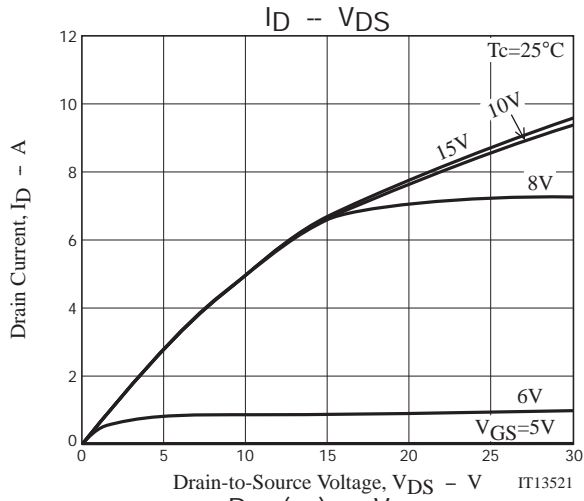
## Switching Time Test Circuit



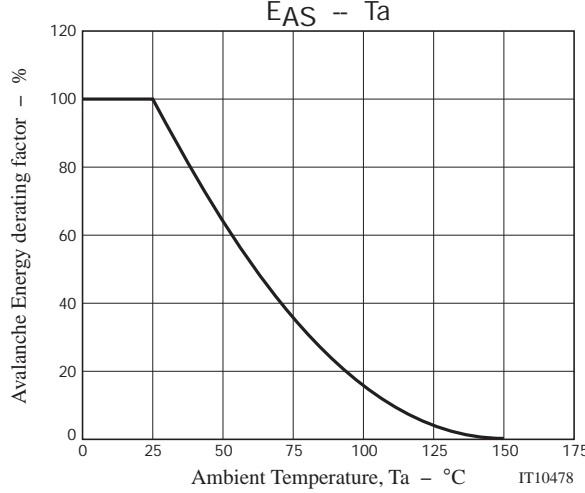
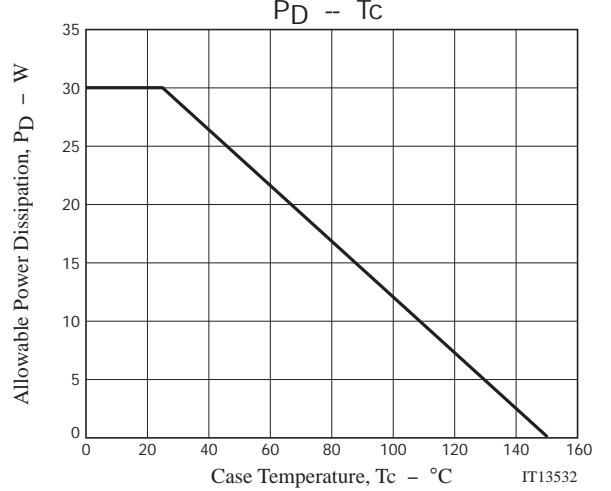
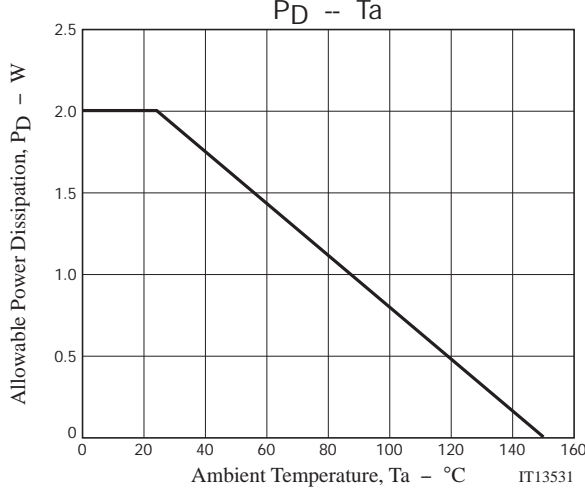
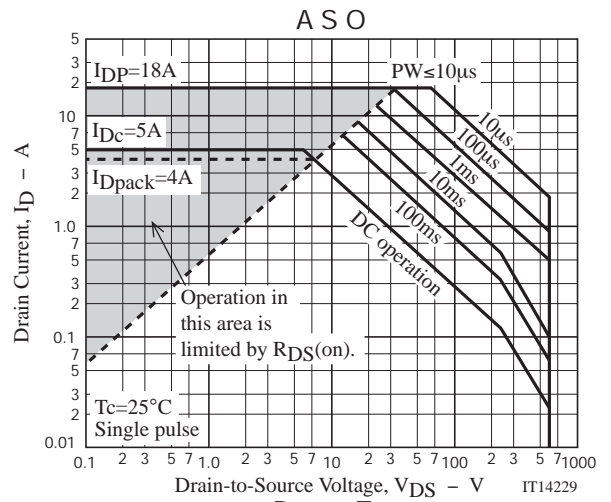
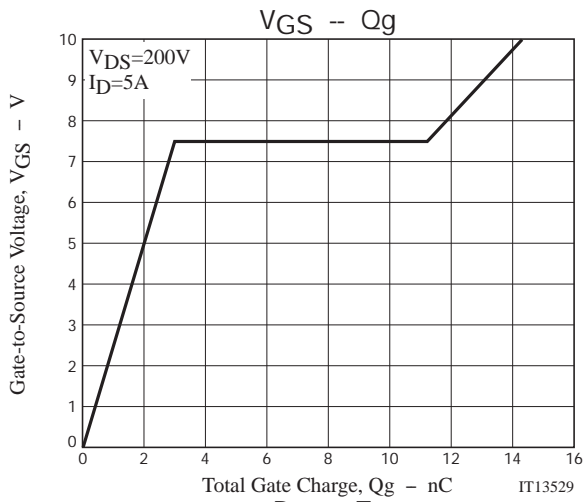
## Avalanche Resistance Test Circuit



# 2SK4198FS



# 2SK4198FS



Note on usage : Since the 2SK4198FS is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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